

isc Silicon NPN Power Transistor

2SC4421

DESCRIPTION

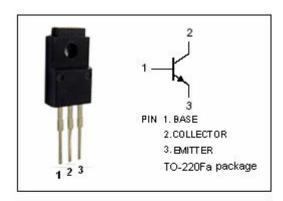
- · Collector-Base Breakdown Voltage-
 - : V_{(BR)CBO}= 500V(Min.)
- Wide Area of Safe Operation
- · High Speed Switching
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

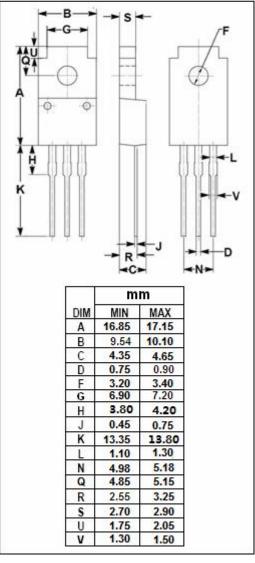
APPLICATIONS

· Designed for high speed switching applications.

ABSOLUTE MAXIMUM RATINGS (Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	500	V
Vces	Collector-Emitter Voltage	500	V
V _{CEO}	Collector-Emitter Voltage	400	V
V _{EBO}	Emitter-Base Voltage	7	V
Ic	Collector Current-Continuous	3	А
I _{CM}	Collector Current-Peak	6	А
I _B	Base Current-Continuous	1.2	А
Pc	Collector Power Dissipation @T _a =25℃	2	
	Collector Power Dissipation @T _C =25°C	40	W
Tj	Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$ C







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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I _C = 10mA; I _B = 0	400			V		
$V_{\text{CE}(\text{sat})}$	Collector-Emitter Saturation Voltage	I _C = 1.5A; I _B = 0.3A			1.5	V		
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 1.5A; I _B = 0.3A			1.5	V		
Ісво	Collector Cutoff Current	V _{CB} = 500V; I _E = 0			100	μА		
ІЕВО	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			100	μА		
h _{FE-1}	DC Current Gain	I _C = 0.1A; V _{CE} = 5V	10					
h _{FE-2}	DC Current Gain	I _C = 1.5A; V _{CE} = 5V	6					
f⊤	Current-Gain—Bandwidth Product	Ic= 0.2A; VcE= 10V; f= 1MHz		5		MHz		
Switching Times								
t _{on}	Turn-on Time				0.5	μ S		
ts	Storage Time	I _C = 1.5A; I _{B1} = 0.3A; I _{B2} = -0.6A; V _{CC} = 150V			2.0	μS		
t _f	Fall Time				0.1	μs		

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